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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	I <sup>2</sup> C, LINbus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, I <sup>2</sup> S, LCD, LVD, POR, PWM, WDT
Number of I/O	50
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	8K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 3.6V
Data Converters	A/D - 16bit
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (10x10)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/nxp-semiconductors/mkl34z64vlh4">https://www.e-xfl.com/product-detail/nxp-semiconductors/mkl34z64vlh4</a>

# Table of Contents

1 Ratings.....	4	3.6.1 ADC electrical specifications.....	26
1.1 Thermal handling ratings.....	4	3.6.2 CMP and 6-bit DAC electrical specifications.....	29
1.2 Moisture handling ratings.....	4	3.7 Timers.....	31
1.3 ESD handling ratings.....	4	3.8 Communication interfaces.....	31
1.4 Voltage and current operating ratings.....	4	3.8.1 SPI switching specifications.....	31
2 General.....	5	3.8.2 Inter-Integrated Circuit Interface (I2C) timing.....	35
2.1 AC electrical characteristics.....	5	3.8.3 UART.....	37
2.2 Nonswitching electrical specifications.....	5	3.9 Human-machine interfaces (HMI).....	37
2.2.1 Voltage and current operating requirements.....	6	3.9.1 LCD electrical characteristics.....	37
2.2.2 LVD and POR operating requirements.....	6	4 Dimensions.....	38
2.2.3 Voltage and current operating behaviors.....	7	4.1 Obtaining package dimensions.....	38
2.2.4 Power mode transition operating behaviors.....	8	5 Pinout.....	39
2.2.5 Power consumption operating behaviors.....	9	5.1 KL34 Signal Multiplexing and Pin Assignments.....	39
2.2.6 EMC radiated emissions operating behaviors.....	15	5.2 KL34 pinouts.....	42
2.2.7 Designing with radiated emissions in mind.....	16	6 Ordering parts.....	44
2.2.8 Capacitance attributes.....	16	6.1 Determining valid orderable parts.....	44
2.3 Switching specifications.....	16	7 Part identification.....	45
2.3.1 Device clock specifications.....	16	7.1 Description.....	45
2.3.2 General switching specifications.....	17	7.2 Format.....	45
2.4 Thermal specifications.....	17	7.3 Fields.....	45
2.4.1 Thermal operating requirements.....	17	7.4 Example.....	45
2.4.2 Thermal attributes.....	17	8 Terminology and guidelines.....	46
3 Peripheral operating requirements and behaviors.....	18	8.1 Definition: Operating requirement.....	46
3.1 Core modules.....	18	8.2 Definition: Operating behavior.....	46
3.1.1 SWD electricals .....	18	8.3 Definition: Attribute.....	46
3.2 System modules.....	19	8.4 Definition: Rating.....	47
3.3 Clock modules.....	20	8.5 Result of exceeding a rating.....	47
3.3.1 MCG specifications.....	20	8.6 Relationship between ratings and operating requirements.....	48
3.3.2 Oscillator electrical specifications.....	22	8.7 Guidelines for ratings and operating requirements.....	48
3.4 Memories and memory interfaces.....	24	8.8 Definition: Typical value.....	48
3.4.1 Flash electrical specifications.....	24	8.9 Typical value conditions.....	49
3.5 Security and integrity modules.....	25	9 Revision history.....	50
3.6 Analog.....	25		

## 1.4 Voltage and current operating ratings

Table 4. Voltage and current operating ratings

Symbol	Description	Min.	Max.	Unit
$V_{DD}$	Digital supply voltage	-0.3	3.8	V
$I_{DD}$	Digital supply current	—	120	mA
$V_{IO}$	IO pin input voltage	-0.3	$V_{DD} + 0.3$	V
$I_D$	Instantaneous maximum current single pin limit (applies to all port pins)	-25	25	mA
$V_{DDA}$	Analog supply voltage	$V_{DD} - 0.3$	$V_{DD} + 0.3$	V

## 2 General

### 2.1 AC electrical characteristics

Unless otherwise specified, propagation delays are measured from the 50% to the 50% point, and rise and fall times are measured at the 20% and 80% points, as shown in the following figure.

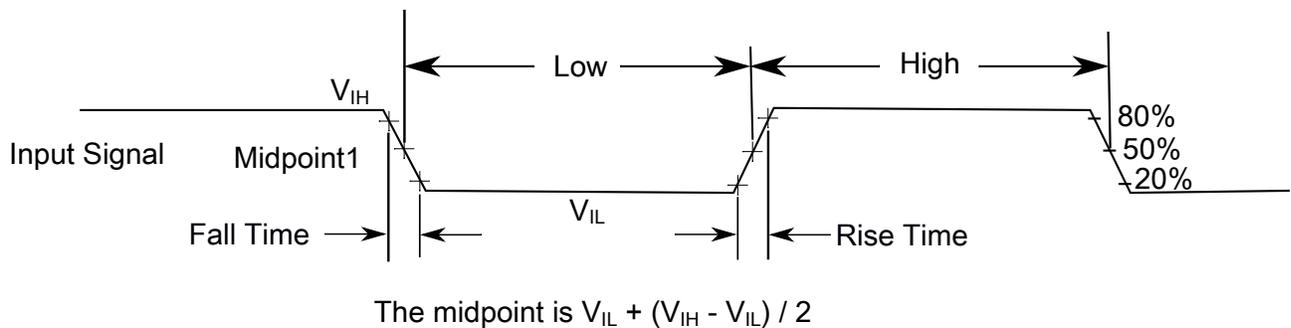


Figure 2. Input signal measurement reference

All digital I/O switching characteristics, unless otherwise specified, assume the output pins have the following characteristics.

- $C_L=30$  pF loads
- Slew rate disabled
- Normal drive strength

### 2.2 Nonswitching electrical specifications

**Table 6. V<sub>DD</sub> supply LVD and POR operating requirements (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V <sub>LVW1H</sub>	<ul style="list-style-type: none"> <li>Level 1 falling (LVWV = 00)</li> </ul>	2.62	2.70	2.78	V	
V <sub>LVW2H</sub>	<ul style="list-style-type: none"> <li>Level 2 falling (LVWV = 01)</li> </ul>	2.72	2.80	2.88	V	
V <sub>LVW3H</sub>	<ul style="list-style-type: none"> <li>Level 3 falling (LVWV = 10)</li> </ul>	2.82	2.90	2.98	V	
V <sub>LVW4H</sub>	<ul style="list-style-type: none"> <li>Level 4 falling (LVWV = 11)</li> </ul>	2.92	3.00	3.08	V	
V <sub>HYSH</sub>	Low-voltage inhibit reset/recover hysteresis — high range	—	±60	—	mV	—
V <sub>LVDL</sub>	Falling low-voltage detect threshold — low range (LVDV=00)	1.54	1.60	1.66	V	—
V <sub>LVW1L</sub>	Low-voltage warning thresholds — low range <ul style="list-style-type: none"> <li>Level 1 falling (LVWV = 00)</li> </ul>	1.74	1.80	1.86	V	1
V <sub>LVW2L</sub>	<ul style="list-style-type: none"> <li>Level 2 falling (LVWV = 01)</li> </ul>	1.84	1.90	1.96	V	
V <sub>LVW3L</sub>	<ul style="list-style-type: none"> <li>Level 3 falling (LVWV = 10)</li> </ul>	1.94	2.00	2.06	V	
V <sub>LVW4L</sub>	<ul style="list-style-type: none"> <li>Level 4 falling (LVWV = 11)</li> </ul>	2.04	2.10	2.16	V	
V <sub>HYSL</sub>	Low-voltage inhibit reset/recover hysteresis — low range	—	±40	—	mV	—
V <sub>BG</sub>	Bandgap voltage reference	0.97	1.00	1.03	V	—
t <sub>LPO</sub>	Internal low power oscillator period — factory trimmed	900	1000	1100	µs	—

1. Rising thresholds are falling threshold + hysteresis voltage

## 2.2.3 Voltage and current operating behaviors

**Table 7. Voltage and current operating behaviors**

Symbol	Description	Min.	Max.	Unit	Notes
V <sub>OH</sub>	Output high voltage — Normal drive pad (except RESET_b) <ul style="list-style-type: none"> <li>2.7 V ≤ V<sub>DD</sub> ≤ 3.6 V, I<sub>OH</sub> = -5 mA</li> <li>1.71 V ≤ V<sub>DD</sub> ≤ 2.7 V, I<sub>OH</sub> = -2.5 mA</li> </ul>	V <sub>DD</sub> - 0.5 V <sub>DD</sub> - 0.5	— —	V V	1, 2
V <sub>OH</sub>	Output high voltage — High drive pad (except RESET_b) <ul style="list-style-type: none"> <li>2.7 V ≤ V<sub>DD</sub> ≤ 3.6 V, I<sub>OH</sub> = -20 mA</li> <li>1.71 V ≤ V<sub>DD</sub> ≤ 2.7 V, I<sub>OH</sub> = -10 mA</li> </ul>	V <sub>DD</sub> - 0.5 V <sub>DD</sub> - 0.5	— —	V V	1, 2
I <sub>OHT</sub>	Output high current total for all ports	—	100	mA	
V <sub>OL</sub>	Output low voltage — Normal drive pad <ul style="list-style-type: none"> <li>2.7 V ≤ V<sub>DD</sub> ≤ 3.6 V, I<sub>OL</sub> = 5 mA</li> <li>1.71 V ≤ V<sub>DD</sub> ≤ 2.7 V, I<sub>OL</sub> = 2.5 mA</li> </ul>	— —	0.5 0.5	V V	1

Table continues on the next page...

**Table 7. Voltage and current operating behaviors (continued)**

Symbol	Description	Min.	Max.	Unit	Notes
V <sub>OL</sub>	Output low voltage — High drive pad <ul style="list-style-type: none"> <li>• 2.7 V ≤ V<sub>DD</sub> ≤ 3.6 V, I<sub>OL</sub> = 20 mA</li> <li>• 1.71 V ≤ V<sub>DD</sub> ≤ 2.7 V, I<sub>OL</sub> = 10 mA</li> </ul>	—	0.5	V	1
		—	0.5	V	
I <sub>OLT</sub>	Output low current total for all ports	—	100	mA	
I <sub>IN</sub>	Input leakage current (per pin) for full temperature range	—	1	μA	3
I <sub>IN</sub>	Input leakage current (per pin) at 25 °C	—	0.025	μA	3
I <sub>IN</sub>	Input leakage current (total all pins) for full temperature range	—		μA	3
I <sub>OZ</sub>	Hi-Z (off-state) leakage current (per pin)	—	1	μA	
R <sub>PU</sub>	Internal pullup resistors	20	50	kΩ	4

1. PTB0, PTB1, PTD6, and PTD7 I/O have both high drive and normal drive capability selected by the associated PTx\_PCRn[DSE] control bit. All other GPIOs are normal drive only.
2. The reset pin only contains an active pull down device when configured as the RESET signal or as a GPIO. When configured as a GPIO output, it acts as a pseudo open drain output.
3. Measured at V<sub>DD</sub> = 3.6 V
4. Measured at V<sub>DD</sub> supply voltage = V<sub>DD</sub> min and V<sub>input</sub> = V<sub>SS</sub>

## 2.2.4 Power mode transition operating behaviors

All specifications except t<sub>POR</sub> and VLLS<sub>x</sub>→RUN recovery times in the following table assume this clock configuration:

- CPU and system clocks = 48 MHz
- Bus and flash clock = 24 MHz
- FEI clock mode

POR and VLLS<sub>x</sub>→RUN recovery use FEI clock mode at the default CPU and system frequency of 21 MHz, and a bus and flash clock frequency of 10.5 MHz.

**Table 8. Power mode transition operating behaviors**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
t <sub>POR</sub>	After a POR event, amount of time from the point V <sub>DD</sub> reaches 1.8 V to execution of the first instruction across the operating temperature range of the chip.	—	—	300	μs	1
	• VLLS0 → RUN	—	113	124	μs	

Table continues on the next page...

**Table 8. Power mode transition operating behaviors (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	• VLLS1 → RUN	—	112	124	μs	
	• VLLS3 → RUN	—	53	60	μs	
	• LLS → RUN	—	4.5	5.0	μs	
	• VLPS → RUN	—	4.5	5.0	μs	
	• STOP → RUN	—	4.5	5.0	μs	

1. Normal boot (FTFA\_FOPT[LPBOOT]=11).

## 2.2.5 Power consumption operating behaviors

The maximum values stated in the following table represent characterized results equivalent to the mean plus three times the standard deviation (mean + 3 sigma).

**Table 9. Power consumption operating behaviors**

Symbol	Description	Typ.	Max	Unit	Note	
I <sub>DDA</sub>	Analog supply current	—	See note	mA	1	
I <sub>DD_RUNCO_CM</sub>	Run mode current in compute operation - 48 MHz core / 24 MHz flash/ bus disabled, LPTMR running using 4 MHz internal reference clock, CoreMark® benchmark code executing from flash, at 3.0 V	—	6.7	mA	2	
I <sub>DD_RUNCO</sub>	Run mode current in compute operation - 48 MHz core / 24 MHz flash / bus clock disabled, code of while(1) loop executing from flash, at 3.0 V	—	4.5	5.1	mA	3
I <sub>DD_RUN</sub>	Run mode current - 48 MHz core / 24 MHz bus and flash, all peripheral clocks disabled, code executing from flash	at 1.8 V	5.6	6.3	mA	3
		at 3.0 V	5.4	6.0	mA	
I <sub>DD_RUN</sub>	Run mode current - 48 MHz core / 24 MHz bus and flash, all peripheral clocks enabled, code executing from flash, at 1.8 V	—	6.9	7.3	mA	3, 4
		at 25 °C	6.9	7.1	mA	
		at 125 °C	7.3	7.6	mA	

Table continues on the next page...

**Table 9. Power consumption operating behaviors (continued)**

Symbol	Description		Typ.	Max	Unit	Note
I <sub>DD_ULLS</sub>	Low leakage stop mode current at 3.0 V	at 25 °C	2.00	2.7	μA	—
		at 50 °C	3.96	5.14	μA	
		at 70 °C	7.77	10.71	μA	
		at 85 °C	14.15	18.79	μA	
		at 105 °C	33.20	43.67	μA	
I <sub>DD_VLLS3</sub>	Very low-leakage stop mode 3 current at 3.0 V	at 25 °C	1.5	2.2	μA	—
		at 50 °C	2.83	3.55	μA	
		at 70 °C	5.53	7.26	μA	
		at 85 °C	9.92	12.71	μA	
		at 105 °C	22.90	29.23	μA	
I <sub>DD_VLLS1</sub>	Very low-leakage stop mode 1 current at 3.0V	at 25 °C	0.71	1.2	μA	—
		at 50 °C	1.27	1.9	μA	
		at 70 °C	2.48	3.51	μA	
		at 85 °C	4.65	6.29	μA	
		at 105 °C	11.55	14.34	μA	
I <sub>DD_VLLS0</sub>	Very low-leakage stop mode 0 current (SMC_STOPCTRL[PORPO] = 0) at 3.0 V	at 25 °C	0.41	0.9	μA	—
		at 50 °C	0.96	1.56	μA	
		at 70 °C	2.17	3.1	μA	
		at 85 °C	4.35	5.32	μA	
		at 105 °C	11.24	14.00	μA	
I <sub>DD_VLLS0</sub>	Very low-leakage stop mode 0 current (SMC_STOPCTRL[PORPO] = 1) at 3.0 V	at 25 °C	0.23	0.69	μA	7
		at 50 °C	0.77	1.35	μA	
		at 70 °C	1.98	2.52	μA	
		at 85 °C	4.16	5.14	μA	
		at 105 °C	11.05	13.80	μA	

1. The analog supply current is the sum of the active or disabled current for each of the analog modules on the device. See each module's specification for its supply current.
2. MCG configured for PEE mode. CoreMark benchmark compiled using IAR 6.40 with optimization level high, optimized for balanced.
3. MCG configured for FEI mode.
4. Incremental current consumption from peripheral activity is not included.
5. MCG configured for BLPI mode. CoreMark benchmark compiled using IAR 6.40 with optimization level high, optimized for balanced.
6. MCG configured for BLPI mode.
7. No brownout.

**Table 10. Low power mode peripheral adders — typical value (continued)**

Symbol	Description	Temperature (°C)						Unit
		-40	25	50	70	85	105	
I <sub>BG</sub>	Bandgap adder when BGEN bit is set and device is placed in VLPx, LLS, or VLLSx mode.	45	45	45	45	45	45	μA
I <sub>ADC</sub>	ADC peripheral adder combining the measured values at V <sub>DD</sub> and V <sub>DDA</sub> by placing the device in STOP or VLPS mode. ADC is configured for low power mode using the internal clock and continuous conversions.	366	366	366	366	366	366	μA
I <sub>LCD</sub>	LCD peripheral adder measured by placing the device in VLLS1 mode with external 32 kHz crystal enabled by means of the OSC0_CR[EREFSTEN, EREFSTEN] bits. VIREG disabled, resistor bias network enabled, 1/8 duty cycle, 8 x 36 configuration for driving 288 Segments, 32 Hz frame rate, no LCD glass connected. Includes ERCLK32K (32 kHz external crystal) power consumption.	5	5	5	5	5	5	μA

### 2.2.5.1 Diagram: Typical IDD\_RUN operating behavior

The following data was measured under these conditions:

- MCG in FBE for run mode, and BLPE for VLPR mode
- No GPIOs toggled
- Code execution from flash with cache enabled
- For the ALLOFF curve, all peripheral clocks are disabled except FTFA

## 2.2.7 Designing with radiated emissions in mind

To find application notes that provide guidance on designing your system to minimize interference from radiated emissions:

1. Go to [www.freescale.com](http://www.freescale.com).
2. Perform a keyword search for “EMC design.”

## 2.2.8 Capacitance attributes

Table 12. Capacitance attributes

Symbol	Description	Min.	Max.	Unit
$C_{IN}$	Input capacitance	—	7	pF

## 2.3 Switching specifications

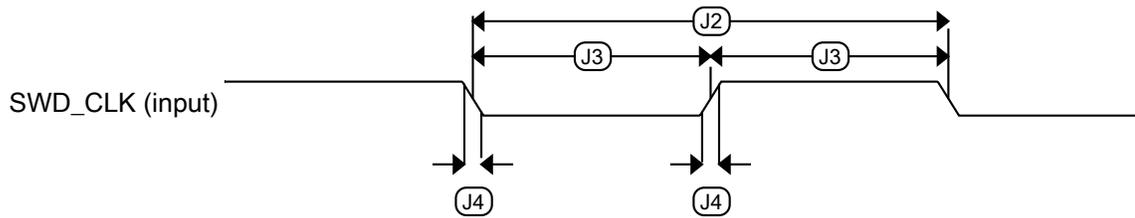
### 2.3.1 Device clock specifications

Table 13. Device clock specifications

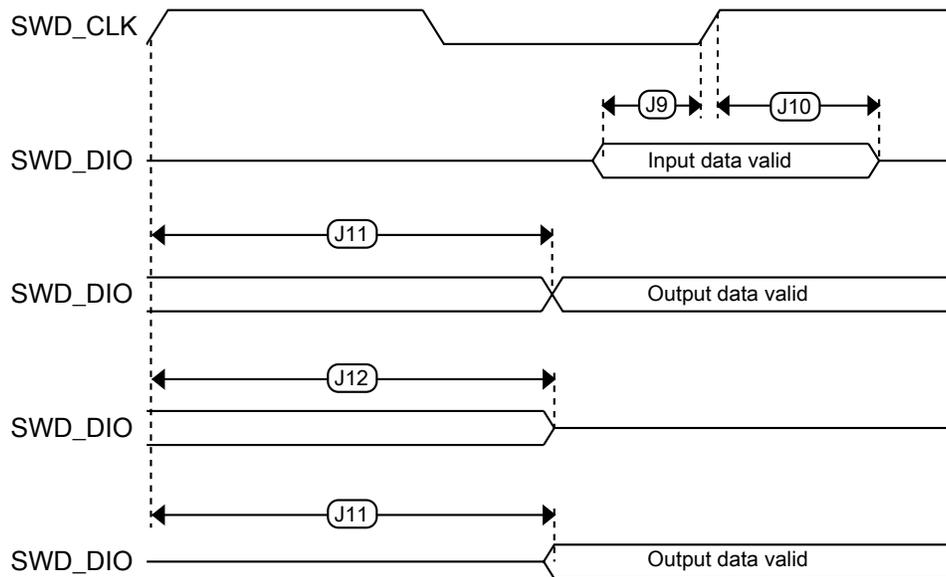
Symbol	Description	Min.	Max.	Unit
Normal run mode				
$f_{SYS}$	System and core clock	—	48	MHz
$f_{BUS}$	Bus clock	—	24	MHz
$f_{FLASH}$	Flash clock	—	24	MHz
$f_{LPTMR}$	LPTMR clock	—	24	MHz
VLPR and VLPS modes <sup>1</sup>				
$f_{SYS}$	System and core clock	—	4	MHz
$f_{BUS}$	Bus clock	—	1	MHz
$f_{FLASH}$	Flash clock	—	1	MHz
$f_{LPTMR}$	LPTMR clock <sup>2</sup>	—	24	MHz
$f_{ERCLK}$	External reference clock	—	16	MHz
$f_{LPTMR\_ERCLK}$	LPTMR external reference clock	—	16	MHz
$f_{osc\_hi\_2}$	Oscillator crystal or resonator frequency — high frequency mode (high range) (MCG_C2[RANGE]=1x)	—	16	MHz
$f_{TPM}$	TPM asynchronous clock	—	8	MHz
$f_{UART0}$	UART0 asynchronous clock	—	8	MHz

**Table 17. SWD full voltage range electricals (continued)**

Symbol	Description	Min.	Max.	Unit
	• Serial wire debug	20	—	ns
J4	SWD_CLK rise and fall times	—	3	ns
J9	SWD_DIO input data setup time to SWD_CLK rise	10	—	ns
J10	SWD_DIO input data hold time after SWD_CLK rise	0	—	ns
J11	SWD_CLK high to SWD_DIO data valid	—	32	ns
J12	SWD_CLK high to SWD_DIO high-Z	5	—	ns



**Figure 5. Serial wire clock input timing**



**Figure 6. Serial wire data timing**

### 3.3.2 Oscillator electrical specifications

#### 3.3.2.1 Oscillator DC electrical specifications

**Table 19. Oscillator DC electrical specifications**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V <sub>DD</sub>	Supply voltage	1.71	—	3.6	V	
I <sub>DDOSC</sub>	Supply current — low-power mode (HGO=0) <ul style="list-style-type: none"> <li>• 32 kHz</li> <li>• 4 MHz</li> <li>• 8 MHz (RANGE=01)</li> <li>• 16 MHz</li> <li>• 24 MHz</li> <li>• 32 MHz</li> </ul>	—	500	—	nA	1
		—	200	—	μA	
		—	300	—	μA	
		—	950	—	μA	
		—	1.2	—	mA	
		—	1.5	—	mA	
I <sub>DDOSC</sub>	Supply current — high gain mode (HGO=1) <ul style="list-style-type: none"> <li>• 32 kHz</li> <li>• 4 MHz</li> <li>• 8 MHz (RANGE=01)</li> <li>• 16 MHz</li> <li>• 24 MHz</li> <li>• 32 MHz</li> </ul>	—	25	—	μA	1
		—	400	—	μA	
		—	500	—	μA	
		—	2.5	—	mA	
		—	3	—	mA	
		—	4	—	mA	
C <sub>x</sub>	EXTAL load capacitance	—	—	—		2, 3
C <sub>y</sub>	XTAL load capacitance	—	—	—		2, 3
R <sub>F</sub>	Feedback resistor — low-frequency, low-power mode (HGO=0)	—	—	—	MΩ	2, 4
	Feedback resistor — low-frequency, high-gain mode (HGO=1)	—	10	—	MΩ	
	Feedback resistor — high-frequency, low-power mode (HGO=0)	—	—	—	MΩ	
	Feedback resistor — high-frequency, high-gain mode (HGO=1)	—	1	—	MΩ	
R <sub>S</sub>	Series resistor — low-frequency, low-power mode (HGO=0)	—	—	—	kΩ	
	Series resistor — low-frequency, high-gain mode (HGO=1)	—	200	—	kΩ	
	Series resistor — high-frequency, low-power mode (HGO=0)	—	—	—	kΩ	
	Series resistor — high-frequency, high-gain mode (HGO=1)					

Table continues on the next page...

**Table 22. Flash command timing specifications (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$t_{ersscr}$	Erase Flash Sector execution time	—	14	114	ms	2
$t_{rd1all}$	Read 1s All Blocks execution time	—	—	1.8	ms	—
$t_{rdonce}$	Read Once execution time	—	—	25	$\mu$ s	1
$t_{pgmonce}$	Program Once execution time	—	65	—	$\mu$ s	—
$t_{ersall}$	Erase All Blocks execution time	—	175	1300	ms	2
$t_{vfykey}$	Verify Backdoor Access Key execution time	—	—	30	$\mu$ s	1

1. Assumes 25 MHz flash clock frequency.
2. Maximum times for erase parameters based on expectations at cycling end-of-life.

### 3.4.1.3 Flash high voltage current behaviors

**Table 23. Flash high voltage current behaviors**

Symbol	Description	Min.	Typ.	Max.	Unit
$I_{DD\_PGM}$	Average current adder during high voltage flash programming operation	—	2.5	6.0	mA
$I_{DD\_ERS}$	Average current adder during high voltage flash erase operation	—	1.5	4.0	mA

### 3.4.1.4 Reliability specifications

**Table 24. NVM reliability specifications**

Symbol	Description	Min.	Typ. <sup>1</sup>	Max.	Unit	Notes
Program Flash						
$t_{nvmretp10k}$	Data retention after up to 10 K cycles	5	50	—	years	—
$t_{nvmretp1k}$	Data retention after up to 1 K cycles	20	100	—	years	—
$n_{nvmcycp}$	Cycling endurance	10 K	50 K	—	cycles	2

1. Typical data retention values are based on measured response accelerated at high temperature and derated to a constant 25 °C use profile. Engineering Bulletin EB618 does not apply to this technology. Typical endurance defined in Engineering Bulletin EB619.
2. Cycling endurance represents number of program/erase cycles at  $-40\text{ °C} \leq T_j \leq 125\text{ °C}$ .

## 3.5 Security and integrity modules

There are no specifications necessary for the device's security and integrity modules.

## 3.6 Analog

### 3.6.1 ADC electrical specifications

All ADC channels meet the 12-bit single-ended accuracy specifications.

#### 3.6.1.1 12-bit ADC operating conditions

Table 25. 12-bit ADC operating conditions

Symbol	Description	Conditions	Min.	Typ. <sup>1</sup>	Max.	Unit	Notes
V <sub>DDA</sub>	Supply voltage	Absolute	1.71	—	3.6	V	—
ΔV <sub>DDA</sub>	Supply voltage	Delta to V <sub>DD</sub> (V <sub>DD</sub> – V <sub>DDA</sub> )	-100	0	+100	mV	2
ΔV <sub>SSA</sub>	Ground voltage	Delta to V <sub>SS</sub> (V <sub>SS</sub> – V <sub>SSA</sub> )	-100	0	+100	mV	2
V <sub>REFH</sub>	ADC reference voltage high		1.13	V <sub>DDA</sub>	V <sub>DDA</sub>	V	
V <sub>REFL</sub>	ADC reference voltage low		V <sub>SSA</sub>	V <sub>SSA</sub>	V <sub>SSA</sub>	V	
V <sub>ADIN</sub>	Input voltage		V <sub>REFL</sub>	—	V <sub>REFH</sub>	V	—
C <sub>ADIN</sub>	Input capacitance	• 8-bit / 10-bit / 12-bit modes	—	4	5	pF	—
R <sub>ADIN</sub>	Input series resistance		—	2	5	kΩ	—
R <sub>AS</sub>	Analog source resistance (external)	12-bit modes f <sub>ADCK</sub> < 4 MHz	—	—	5	kΩ	3
f <sub>ADCK</sub>	ADC conversion clock frequency	≤ 12-bit mode	1.0	—	18.0	MHz	4
C <sub>rate</sub>	ADC conversion rate	≤ 12-bit modes No ADC hardware averaging Continuous conversions enabled, subsequent conversion time	20.000	—	818.330	Ksps	5

1. Typical values assume V<sub>DDA</sub> = 3.0 V, Temp = 25 °C, f<sub>ADCK</sub> = 1.0 MHz, unless otherwise stated. Typical values are for reference only, and are not tested in production.
2. DC potential difference.
3. This resistance is external to MCU. To achieve the best results, the analog source resistance must be kept as low as possible. The results in this data sheet were derived from a system that had < 8 Ω analog source resistance. The R<sub>AS</sub>/C<sub>AS</sub> time constant should be kept to < 1 ns.
4. To use the maximum ADC conversion clock frequency, CFG2[ADHSC] must be set and CFG1[ADLPC] must be clear.
5. For guidelines and examples of conversion rate calculation, download the [ADC calculator tool](#).

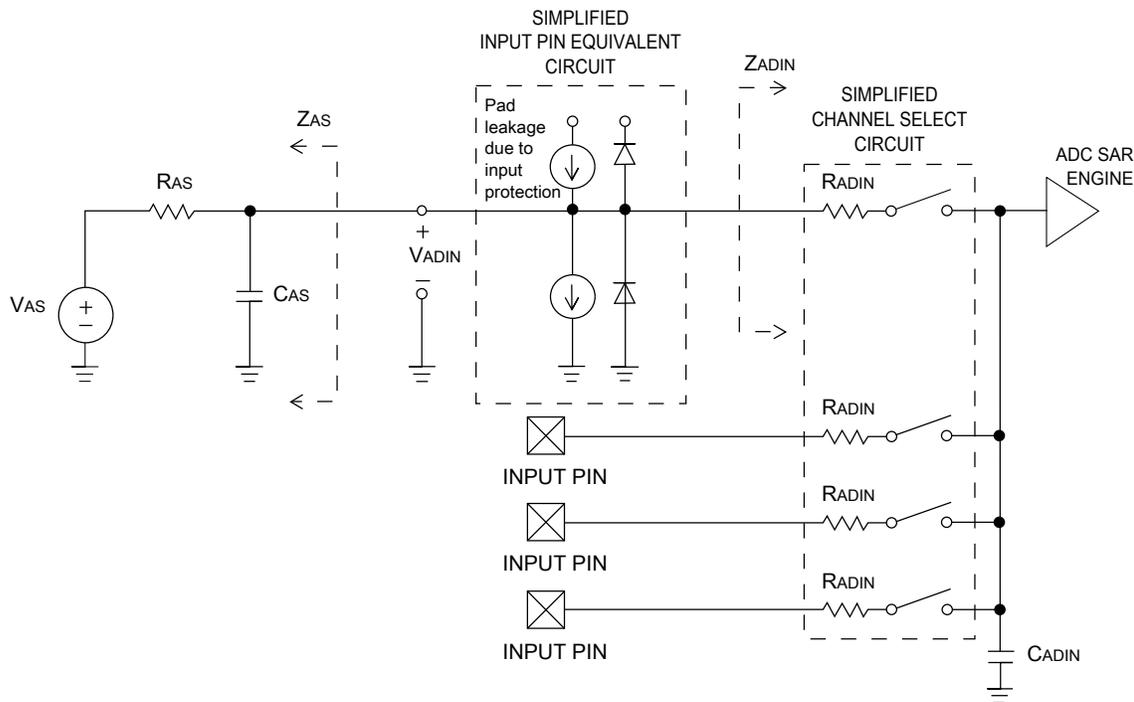


Figure 7. ADC input impedance equivalency diagram

### 3.6.1.2 12-bit ADC electrical characteristics

Table 26. 12-bit ADC characteristics ( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SSA}$ )

Symbol	Description	Conditions <sup>1</sup>	Min.	Typ. <sup>2</sup>	Max.	Unit	Notes
$I_{DDA\_ADC}$	Supply current		0.215	—	1.7	mA	3
$f_{ADACK}$	ADC asynchronous clock source	• ADLPC = 1, ADHSC = 0	1.2	2.4	3.9	MHz	$t_{ADACK} = 1/f_{ADACK}$
		• ADLPC = 1, ADHSC = 1	2.4	4.0	6.1	MHz	
		• ADLPC = 0, ADHSC = 0	3.0	5.2	7.3	MHz	
		• ADLPC = 0, ADHSC = 1	4.4	6.2	9.5	MHz	
	Sample Time	See Reference Manual chapter for sample times					
TUE	Total unadjusted error	• 12-bit modes • <12-bit modes	—	±4 ±1.4	±6.8 ±2.1	LSB <sup>4</sup>	5
DNL	Differential non-linearity	• 12-bit modes • <12-bit modes	—	±0.7 ±0.2	-1.1 to +1.9 -0.3 to 0.5	LSB <sup>4</sup>	5

Table continues on the next page...

**Table 26. 12-bit ADC characteristics ( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SSA}$ ) (continued)**

Symbol	Description	Conditions <sup>1</sup>	Min.	Typ. <sup>2</sup>	Max.	Unit	Notes
INL	Integral non-linearity	<ul style="list-style-type: none"> <li>12-bit modes</li> <li>&lt;12-bit modes</li> </ul>	—	±1.0	-2.7 to +1.9	LSB <sup>4</sup>	5
E <sub>FS</sub>	Full-scale error	<ul style="list-style-type: none"> <li>12-bit modes</li> <li>&lt;12-bit modes</li> </ul>	—	-4	-5.4	LSB <sup>4</sup>	$V_{ADIN} = V_{DDA}$ <sup>5</sup>
E <sub>Q</sub>	Quantization error	<ul style="list-style-type: none"> <li>12-bit modes</li> </ul>	—	—	±0.5	LSB <sup>4</sup>	
E <sub>IL</sub>	Input leakage error		$I_{in} \times R_{AS}$			mV	$I_{in}$ = leakage current (refer to the MCU's voltage and current operating ratings)
	Temp sensor slope	Across the full temperature range of the device	1.55	1.62	1.69	mV/°C	6
V <sub>TEMP25</sub>	Temp sensor voltage	25 °C	706	716	726	mV	6

1. All accuracy numbers assume the ADC is calibrated with  $V_{REFH} = V_{DDA}$
2. Typical values assume  $V_{DDA} = 3.0$  V, Temp = 25 °C,  $f_{ADCK} = 2.0$  MHz unless otherwise stated. Typical values are for reference only and are not tested in production.
3. The ADC supply current depends on the ADC conversion clock speed, conversion rate and ADC\_CFG1[ADLPC] (low power). For lowest power operation, ADC\_CFG1[ADLPC] must be set, the ADC\_CFG2[ADHSC] bit must be clear with 1 MHz ADC conversion clock speed.
4.  $1 \text{ LSB} = (V_{REFH} - V_{REFL})/2^N$
5. ADC conversion clock < 16 MHz, Max hardware averaging (AVGE = %1, AVGS = %11)
6. ADC conversion clock < 3 MHz

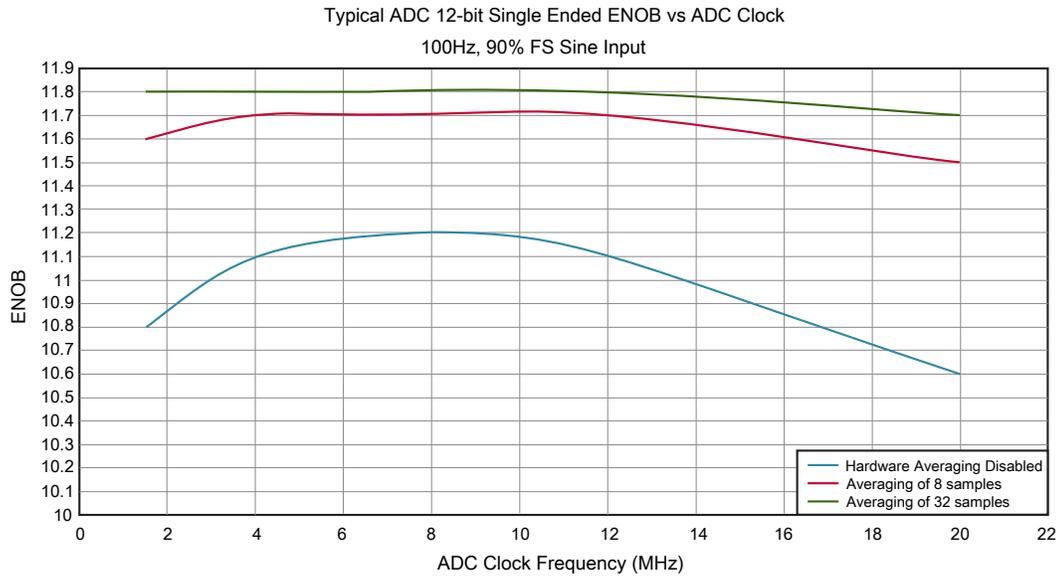


Figure 8. Typical ENOB vs. ADC\_CLK for 12-bit single-ended mode

### 3.6.2 CMP and 6-bit DAC electrical specifications

Table 27. Comparator and 6-bit DAC electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit
$V_{DD}$	Supply voltage	1.71	—	3.6	V
$I_{DDHS}$	Supply current, High-speed mode (EN=1, PMODE=1)	—	—	200	$\mu$ A
$I_{DDL S}$	Supply current, low-speed mode (EN=1, PMODE=0)	—	—	20	$\mu$ A
$V_{AIN}$	Analog input voltage	$V_{SS} - 0.3$	—	$V_{DD}$	V
$V_{AIO}$	Analog input offset voltage	—	—	20	mV
$V_H$	Analog comparator hysteresis <sup>1</sup> <ul style="list-style-type: none"> <li>• CR0[HYSTCTR] = 00</li> <li>• CR0[HYSTCTR] = 01</li> <li>• CR0[HYSTCTR] = 10</li> <li>• CR0[HYSTCTR] = 11</li> </ul>	—	5 10 20 30	—	mV
$V_{CMPOh}$	Output high	$V_{DD} - 0.5$	—	—	V
$V_{CMPOl}$	Output low	—	—	0.5	V
$t_{DHS}$	Propagation delay, high-speed mode (EN=1, PMODE=1)	20	50	200	ns
$t_{DLS}$	Propagation delay, low-speed mode (EN=1, PMODE=0)	80	250	600	ns
	Analog comparator initialization delay <sup>2</sup>	—	—	40	$\mu$ s

Table continues on the next page...

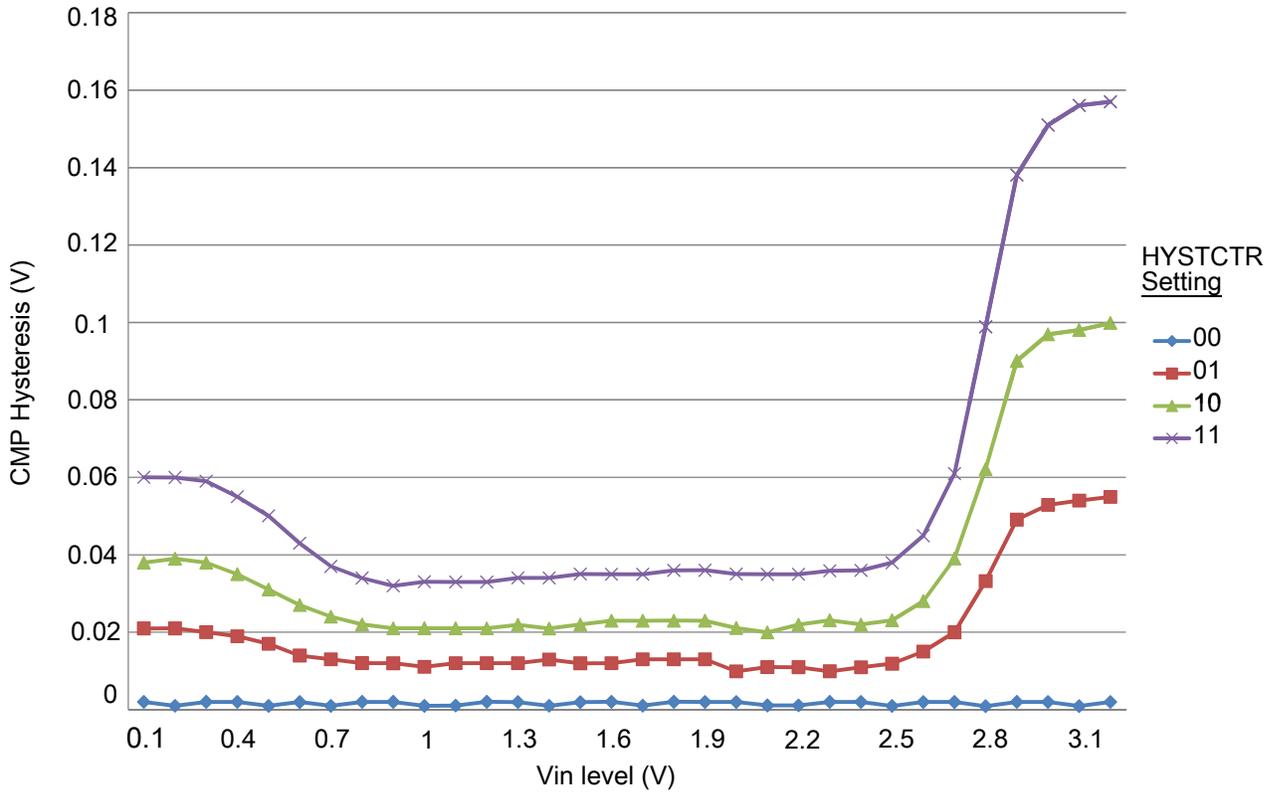


Figure 10. Typical hysteresis vs. Vin level (VDD = 3.3 V, PMODE = 1)

### 3.7 Timers

See [General switching specifications](#).

### 3.8 Communication interfaces

#### 3.8.1 SPI switching specifications

The Serial Peripheral Interface (SPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The following tables provide timing characteristics for classic SPI timing modes. See the SPI chapter of the chip's Reference Manual for information about the modified transfer formats used for communicating with slower peripheral devices.

**Table 33. LCD electricals (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$I_{VREG}$	$V_{IREG}$ current adder — $RVEN = 1$	—	1	—	$\mu A$	4
$I_{RBIAS}$	RBIAS current adder					
	<ul style="list-style-type: none"> <li>LADJ = 10 or 11 — High load (LCD glass capacitance <math>\leq 8000</math> pF)</li> <li>LADJ = 00 or 01 — Low load (LCD glass capacitance <math>\leq 2000</math> pF)</li> </ul>	—	10	—	$\mu A$	
$R_{RBIAS}$	RBIAS resistor values					
	<ul style="list-style-type: none"> <li>LADJ = 10 or 11 — High load (LCD glass capacitance <math>\leq 8000</math> pF)</li> <li>LADJ = 00 or 01 — Low load (LCD glass capacitance <math>\leq 2000</math> pF)</li> </ul>	—	0.28	—	$M\Omega$	
VLL1	VLL1 voltage	—	—	$V_{IREG}$	V	5
VLL2	VLL2 voltage	—	—	$2 \times V_{IREG}$	V	5
VLL3	VLL3 voltage	—	—	$3 \times V_{IREG}$	V	5
VLL1	VLL1 voltage	—	—	$V_{DDA} / 3$	V	6
VLL2	VLL2 voltage	—	—	$V_{DDA} / 1.5$	V	6
VLL3	VLL3 voltage	—	—	$V_{DDA}$	V	6

- The actual value used could vary with tolerance.
- For highest glass capacitance values, LCD\_GCR[LADJ] should be configured as specified in the LCD Controller chapter within the device's reference manual.
- $V_{IREG}$  maximum should never be externally driven to any level other than  $V_{DD} - 0.15$  V
- 2000 pF load LCD, 32 Hz frame frequency
- VLL1, VLL2 and VLL3 are a function of  $V_{IREG}$  only when the regulator is enabled (GCR[RVEN]=1) and the charge pump is enabled (GCR[CPSEL]=1).
- VLL1, VLL2 and VLL3 are a function of  $V_{DDA}$  only under either of the following conditions:
  - The charge pump is enabled (GCR[CPSEL]=1), the regulator is disabled (GCR[RVEN]=0), and VLL3 =  $V_{DDA}$  through the internal power switch (GCR[VSUPPLY]=0).
  - The resistor bias string is enabled (GCR[CPSEL]=0), the regulator is disabled (GCR[RVEN]=0), and VLL3 is connected to  $V_{DDA}$  externally (GCR[VSUPPLY]=1).

## 4 Dimensions

### 4.1 Obtaining package dimensions

Package dimensions are provided in package drawings.

To find a package drawing, go to [freescale.com](http://freescale.com) and perform a keyword search for the drawing's document number:



## Pinout

100 LQFP	64 LQFP	Pin Name	Default	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7	EzPort
20	11	PTE22	ADC0_SE3	ADC0_SE3	PTE22		TPM2_CH0	UART2_TX				
21	12	PTE23	ADC0_SE7a	ADC0_SE7a	PTE23		TPM2_CH1	UART2_RX				
22	13	VDDA	VDDA	VDDA								
23	14	VREFH	VREFH	VREFH								
24	15	VREFL	VREFL	VREFL								
25	16	VSSA	VSSA	VSSA								
26	17	PTE29	CMP0_IN5/ ADC0_SE4b	CMP0_IN5/ ADC0_SE4b	PTE29		TPM0_CH2	TPM_ CLKIN0				
27	18	PTE30	ADC0_SE23/ CMP0_IN4	ADC0_SE23/ CMP0_IN4	PTE30		TPM0_CH3	TPM_ CLKIN1				
28	19	PTE31	DISABLED		PTE31		TPM0_CH4					
29	—	VSS	VSS	VSS								
30	—	VDD	VDD	VDD								
31	20	PTE24	DISABLED		PTE24		TPM0_CH0		I2C0_SCL			
32	21	PTE25	DISABLED		PTE25		TPM0_CH1		I2C0_SDA			
33	—	PTE26	DISABLED		PTE26		TPM0_CH5			RTC_ CLKOUT		
34	22	PTA0	SWD_CLK		PTA0		TPM0_CH5				SWD_CLK	
35	23	PTA1	DISABLED		PTA1	UART0_RX	TPM2_CH0					
36	24	PTA2	DISABLED		PTA2	UART0_TX	TPM2_CH1					
37	25	PTA3	SWD_DIO		PTA3	I2C1_SCL	TPM0_CH0				SWD_DIO	
38	26	PTA4	NMI_b		PTA4	I2C1_SDA	TPM0_CH1				NMI_b	
39	27	PTA5	DISABLED		PTA5		TPM0_CH2					
40	—	PTA6	DISABLED		PTA6		TPM0_CH3					
41	—	PTA7	DISABLED		PTA7		TPM0_CH4					
42	28	PTA12	DISABLED		PTA12		TPM1_CH0					
43	29	PTA13	DISABLED		PTA13		TPM1_CH1					
44	—	PTA14	DISABLED		PTA14	SPI0_PCS0	UART0_TX					
45	—	PTA15	DISABLED		PTA15	SPI0_SCK	UART0_RX					
46	—	PTA16	DISABLED		PTA16	SPI0_MOSI			SPI0_MISO			
47	—	PTA17	DISABLED		PTA17	SPI0_MISO			SPI0_MISO			
48	30	VDD	VDD	VDD								
49	31	VSS	VSS	VSS								
50	32	PTA18	EXTAL0	EXTAL0	PTA18		UART1_RX	TPM_ CLKIN0				
51	33	PTA19	XTAL0	XTAL0	PTA19		UART1_TX	TPM_ CLKIN1		LPTMR0_ ALT1		
52	34	PTA20	RESET_b		PTA20						RESET_b	
53	35	PTB0/ LLWU_P5	LCD_P0/ ADC0_SE8	LCD_P0/ ADC0_SE8	PTB0/ LLWU_P5	I2C0_SCL	TPM1_CH0				LCD_P0	
54	36	PTB1	LCD_P1/ ADC0_SE9	LCD_P1/ ADC0_SE9	PTB1	I2C0_SDA	TPM1_CH1				LCD_P1	

## 7.4 Example

This is an example part number:

MKL34Z64VLL4

## 8 Terminology and guidelines

### 8.1 Definition: Operating requirement

An *operating requirement* is a specified value or range of values for a technical characteristic that you must guarantee during operation to avoid incorrect operation and possibly decreasing the useful life of the chip.

#### 8.1.1 Example

This is an example of an operating requirement:

Symbol	Description	Min.	Max.	Unit
V <sub>DD</sub>	1.0 V core supply voltage	0.9	1.1	V

### 8.2 Definition: Operating behavior

Unless otherwise specified, an *operating behavior* is a specified value or range of values for a technical characteristic that are guaranteed during operation if you meet the operating requirements and any other specified conditions.

### 8.3 Definition: Attribute

An *attribute* is a specified value or range of values for a technical characteristic that are guaranteed, regardless of whether you meet the operating requirements.

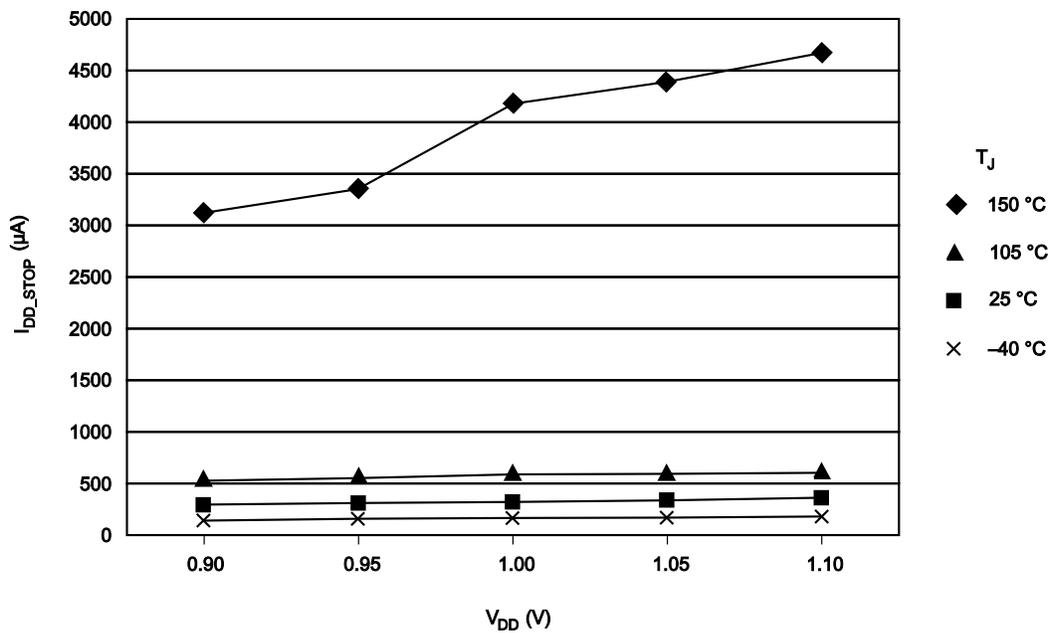
### 8.8.1 Example 1

This is an example of an operating behavior that includes a typical value:

Symbol	Description	Min.	Typ.	Max.	Unit
$I_{WP}$	Digital I/O weak pullup/pulldown current	10	70	130	$\mu\text{A}$

### 8.8.2 Example 2

This is an example of a chart that shows typical values for various voltage and temperature conditions:



## 8.9 Typical value conditions

Typical values assume you meet the following conditions (or other conditions as specified):